

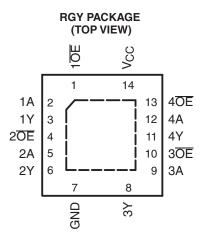
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# **QUADRUPLE BUS BUFFER GATE WITH 3-STATE OUTPUTS**

Check for Samples: SN74LV125A-Q1

#### **FEATURES**

- Qualified for Automotive Applications
- 2-V to 5.5-V V<sub>CC</sub> Operation
- Typical V<sub>OLP</sub> (Output Ground Bounce)
  <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)
  >2.3 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Support Mixed-Mode Voltage Operation on All Ports
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation



#### DESCRIPTION

The SN74LV125A-Q1 quadruple bus buffer gate is designed for 2-V to 5.5-V V<sub>CC</sub> operation.

This device features independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable  $(\overline{OE})$  input is high.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

#### **ORDERING INFORMATION**

| T <sub>A</sub> | PACK      | AGE <sup>(1)</sup> | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|-----------|--------------------|-----------------------|------------------|
| -40°C to 125°C | QFN – RGY | Reel of 3000       | SN74LV125AQRGYRQ1     | LV125Q           |

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



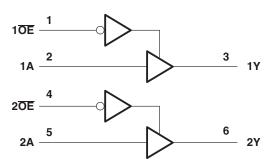
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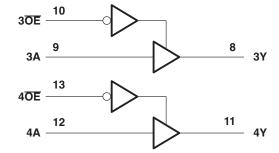


# FUNCTION TABLE (EACH BUFFER)

| INPL | OUTPUT |   |
|------|--------|---|
| ŌĒ   | Α      | Y |
| L    | Н      | Н |
| L    | L      | L |
| Н    | Χ      | Z |

# **LOGIC DIAGRAM (POSITIVE LOGIC)**





# **ABSOLUTE MAXIMUM RATINGS**(1)

over operating free-air temperature range (unless otherwise noted)

|                  |  | •                     | MIN            | MAX | UNIT |
|------------------|--|-----------------------|----------------|-----|------|
| $V_{CC}$         | Supply voltage range                                   |                       | -0.5           | 7   | V    |
| $V_{I}$          | Input voltage range (2)                                | -0.5                  | 7              | V   |      |
| Vo               | Voltage range applied to any output in the high-impeda | -0.5                  | 7              | V   |      |
| Vo               | Output voltage range <sup>(2)</sup> (3)                | -0.5                  | $V_{CC} + 0.5$ | V   |      |
| I <sub>IK</sub>  | Input clamp current                                    | V <sub>I</sub> < 0    |                | -20 | mA   |
| I <sub>OK</sub>  | Output clamp current                                   | V <sub>O</sub> < 0    |                | -50 | mA   |
| Io               | Continuous output current                              | $V_O = 0$ to $V_{CC}$ |                | ±35 | mA   |
|                  | Continuous current through V <sub>CC</sub> or GND      |                       |                | ±70 | mA   |
| $\theta_{JA}$    | Package thermal impedance <sup>(4)</sup>               | RGY package           |                | 47  | °C/W |
| T <sub>stg</sub> | Storage temperature range                              | -65                   | 150            | °C  |      |

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> This value is limited to 5.5 V maximum.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51-5.



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# **RECOMMENDED OPERATING CONDITIONS**(1)

|                 |                                    |  | MIN                   | MAX                   | UNIT |  |  |
|-----------------|------------------------------------|--|-----------------------|-----------------------|------|--|--|
| V <sub>CC</sub> | Supply voltage                     |  | 4.5                   | 5.5                   | V    |  |  |
|                 |                                    | V <sub>CC</sub> = 2 V                      | 1.5                   |                       |      |  |  |
| \ /             | High level inner college           | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | V <sub>CC</sub> x 0.7 |                       |      |  |  |
| $V_{IH}$        | High-level input voltage           | V <sub>CC</sub> = 3 V to 3.6 V             | V <sub>CC</sub> x 0.7 |                       | V    |  |  |
|                 |                                    | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | V <sub>CC</sub> x 0.7 |                       |      |  |  |
|                 |                                    | V <sub>CC</sub> = 2 V                      |                       | 0.5                   |      |  |  |
| V               | Lauran in mark walka na            | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ |                       | V <sub>CC</sub> x 0.3 | V    |  |  |
| $V_{IL}$        | Low-level input voltage            | V <sub>CC</sub> = 3 V to 3.6 V             |                       | V <sub>CC</sub> x 0.3 | V    |  |  |
|                 |                                    | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ |                       | $V_{CC} \times 0.3$   |      |  |  |
| $V_{I}$         | Input voltage                      |  | 0                     | 5.5                   | V    |  |  |
| V               | Output voltage                     | High or low state                          | 0                     | $V_{CC}$              | V    |  |  |
| Vo              | Output voltage                     | 3-state                                    | 0                     | 5.5                   | V    |  |  |
|                 |                                    | V <sub>CC</sub> = 2 V                      |                       | -50                   |      |  |  |
|                 | High lovel output ourrent          | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ |                       | -2                    | mA   |  |  |
| I <sub>OH</sub> | High-level output current          | $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$   |                       | -8                    | MA   |  |  |
|                 |                                    | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ |                       | -16                   |      |  |  |
|                 |                                    | $V_{CC} = 2 V$                             |                       | 50                    |      |  |  |
|                 | Low lovel output ourrent           | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ |                       | 2                     | A    |  |  |
| l <sub>OL</sub> | Low-level output current           | $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$   |                       | 8                     | mA   |  |  |
|                 |                                    | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ |                       | 16                    |      |  |  |
|                 |                                    | $V_{CC}$ = 2.3 V to 2.7 V                  |                       | 200                   |      |  |  |
| Δt/Δν           | Input transition rise or fall rate | V <sub>CC</sub> = 3 V to 3.6 V             |                       | 100                   |      |  |  |
|                 |                                    | V <sub>CC</sub> = 4.5 V to 5.5 V           |                       | 20                    |      |  |  |
| T <sub>A</sub>  | Operating free-air temperature     |  | -40                   | 125                   | °C   |  |  |

<sup>(1)</sup> All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER        | TEST CONDITIONS                  | V <sub>CC</sub> | MIN                  | TYP | MAX  | UNIT |
|------------------|----------------------------------|-----------------|----------------------|-----|------|------|
|                  | I <sub>OH</sub> = -50 μA         | 2 V to 5.5 V    | V <sub>CC</sub> -0.1 |     |      |      |
| V                | $I_{OH} = -2 \text{ mA}$         | 2.3 V           | 2                    |     |      |      |
| V <sub>OH</sub>  | $I_{OH} = -8 \text{ mA}$         | 3 V             | 2.48                 |     |      | V    |
|                  | $I_{OH} = -16 \text{ mA}$        | 4.5 V           | 3.8                  |     |      |      |
|                  | I <sub>OL</sub> = 50 μA          | 2 V to 5.5 V    |                      |     | 0.1  |      |
| V                | I <sub>OH</sub> = 2 mA           | 2.3 V           |                      |     | 0.4  | V    |
| $V_{OL}$         | I <sub>OH</sub> = 8 mA           | 3 V             |                      |     | 0.44 | V    |
|                  | I <sub>OL</sub> = 16 mA          | 4.5 V           |                      |     | 0.55 |      |
| I <sub>I</sub>   | V <sub>I</sub> = 5.5 V or GND    | 0 to 5.5 V      |                      |     | ±1   | μА   |
| l <sub>OZ</sub>  | $V_O = V_{CC}$ or GND            | 5.5 V           |                      |     | ±5   | μΑ   |
| I <sub>CC</sub>  | $V_I = V_{CC}$ or GND, $I_O = 0$ | 5.5 V           |                      |     | 20   | μΑ   |
| I <sub>off</sub> | $V_I$ or $V_O = 0$ to 5.5 V      | 0               |                      |     | 5    | μΑ   |
| 6                | V V or CND                       | 3.3 V           |                      | 1.6 |      | "r   |
| $C_{i}$          | $V_I = V_{CC}$ or GND            | 5 V             |                      | 1.6 |      | pF   |

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# **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$  (unless otherwise noted) (see Figure 1)

| PARAMETER          | FROM<br>(INPUT) | TO (OUTPUT) | LOAD<br>CAPACITANCE   | T <sub>A</sub> =25°C | T <sub>A=</sub><br>-40°C to 125°C | UNIT |
|--------------------|-----------------|-------------|-----------------------|----------------------|-----------------------------------|------|
|                    | (INPOT)         | (OUTPUT)    | CAPACITANCE           | MIN TYP MAX          | MIN MAX                           |      |
| t <sub>pd</sub>    | Α               | Υ           |                       | 8.7 16.5             | 1 18.5                            | ns   |
| t <sub>en</sub>    | ŌĒ              | Υ           | C                     | 8.8 16.5             | 1 18.5                            | ns   |
| t <sub>dis</sub>   | ŌĒ              | Y           | $C_L = 50 \text{ pF}$ | 7.3 18.2             | 1 20.5                            | ns   |
| t <sub>sk(o)</sub> |                 |             |                       | 2                    |                                   | ns   |

#### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$  (unless otherwise noted) (see Figure 1)

| PARAMETER          | FROM    | TO (OUTPUT) | LOAD                  | TA  | = 25° | С    | T <sub>A=</sub><br>-40°C to 1 | UNIT |    |
|--------------------|---------|-------------|-----------------------|-----|-------|------|-------------------------------|------|----|
|                    | (INPUT) | (OUTPUT)    | CAPACITANCE           | MIN | TYP   | MAX  | MIN                           | MAX  |    |
| t <sub>pd</sub>    | А       | Υ           |                       |     | 6.1   | 11.5 | 1                             | 13   | ns |
| t <sub>en</sub>    | ŌĒ      | Υ           | C 50 pF               |     | 6.2   | 11.5 | 1                             | 13   | ns |
| t <sub>dis</sub>   | ŌĒ      | Υ           | $C_L = 50 \text{ pF}$ |     | 5.5   | 13.2 | 1                             | 15   | ns |
| t <sub>sk(o)</sub> |         |             |                       |     |       | 1.5  |                               |      | ns |

# **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $V_{CC}$  = 5 V  $\pm$  0.5 V (unless otherwise noted) (see Figure 1)

| PARAMETER          | FROM    | TO       | LOAD<br>CAPACITANCE   | T <sub>A</sub> =25°C |     | T <sub>A=</sub><br>-40°C to 1 | 25°C | UNIT |
|--------------------|---------|----------|-----------------------|----------------------|-----|-------------------------------|------|------|
|                    | (INPUT) | (OUTPUT) | CAPACITANCE           | MIN TYP M            | AX  | MIN                           | MAX  |      |
| t <sub>pd</sub>    | Α       | Υ        |                       | 4.3                  | 7.5 |                               | 10   | ns   |
| t <sub>en</sub>    | OE      | Υ        | C 50 pF               | 4.4                  | 7.1 |                               | 10   | ns   |
| t <sub>dis</sub>   | OE      | Υ        | $C_L = 50 \text{ pF}$ | 4                    | 8.8 |                               | 11   | ns   |
| t <sub>sk(o)</sub> |         |          |                       |                      | 1   |                               |      | ns   |

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# NOISE CHARACTERISTICS(1)

 $V_{CC}$  = 3.3 V,  $C_L$  = 50 pF,  $T_A$  = 25°C

|                    |   | MIN  | TYP  | MAX  | UNIT |
|--------------------|---|------|------|------|------|
| $V_{OL(P)}$        | Quiet output, maximum dynamic V <sub>OL</sub> |      | 0.4  | 0.8  | V    |
| $V_{OL(V)}$        | Quiet output, minimum dynamic V <sub>OL</sub> |      | -0.3 | -0.8 | V    |
| V <sub>OH(V)</sub> | Quiet output, minimum dynamic V <sub>OH</sub> |      | 3    |      | V    |
| V <sub>IH(D)</sub> | High-level dynamic input voltage              | 2.31 |      |      | V    |
| $V_{IL(D)}$        | Low-level dynamic input voltage               |      |      | 0.99 | V    |

<sup>(1)</sup> Characteristics are for surface-mount packages only.

# **OPERATING CHARACTERISTICS**

 $T_A = 25^{\circ}C$ 

|   | PARAMETER                     | TEST CC         | NDITIONS            | V <sub>CC</sub> | TYP   | UNIT |      |
|---|-------------------------------|-----------------|---------------------|-----------------|-------|------|------|
|   | Dower discipation conscitones | Outpute enabled | C <sub>L</sub> = 50 | f = 10          | 3.3 V | 15.5 | ~ F  |
| C <sub>pd</sub> Power dissipation capacitance |                               | Outputs enabled | pF,                 | MHz             | 5 V   | 17.6 | + p⊢ |

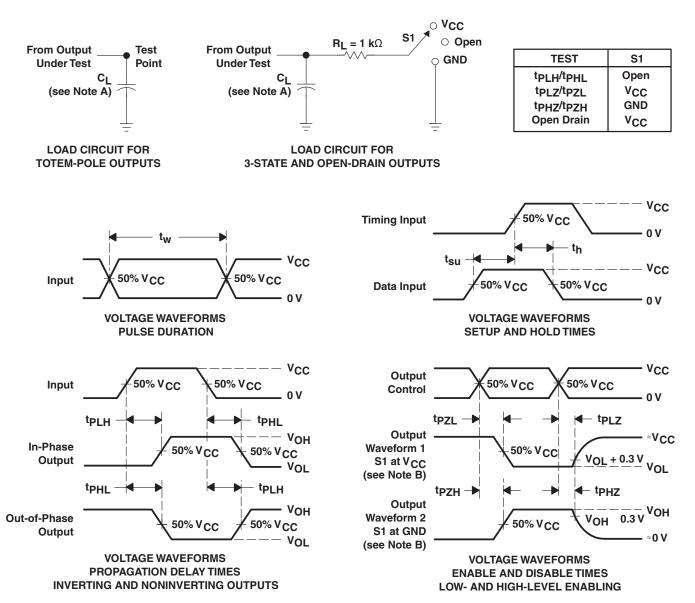
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#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristicsPRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  3 ns,  $t_f \leq$  3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpHL and tpLH are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuits and Voltage Waveforms





10-Dec-2020

#### PACKAGING INFORMATION

| Orderable Device  | Status (1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan     | Lead finish/<br>Ball material | MSL Peak Temp       | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|-------------------|------------|--------------|--------------------|------|----------------|--------------|-------------------------------|---------------------|--------------|-------------------------|---------|
| SN74LV125AQRGYRQ1 | ACTIVE     | VQFN         | RGY                | 14   | 2000           | RoHS & Green | NIPDAU                        | Level-3-260C-168 HR | -40 to 125   | LV125Q                  | Samples |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

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Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN74LV125A-Q1:



# **PACKAGE OPTION ADDENDUM**

10-Dec-2020

• Catalog: SN74LV125A

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Jun-2022

# TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width     |
|----|---|
| В0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device            | U    | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|-------------------|------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| SN74LV125AQRGYRQ1 | VQFN | RGY                | 14 | 2000 | 330.0                    | 12.4                     | 3.75       | 3.75       | 1.15       | 8.0        | 12.0      | Q1               |

# **PACKAGE MATERIALS INFORMATION**

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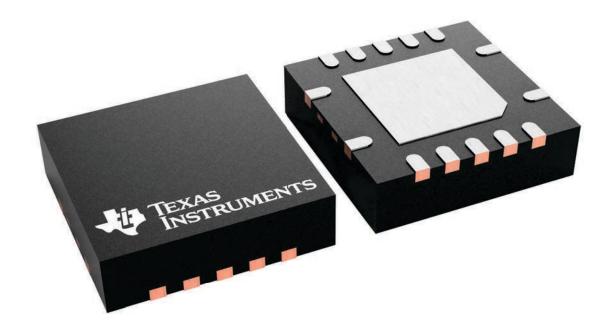
## \*All dimensions are nominal

| Device            | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |  |
|-------------------|--------------|-----------------|------|------|-------------|------------|-------------|--|
| SN74LV125AQRGYRQ1 | VQFN         | RGY             | 14   | 2000 | 356.0       | 356.0      | 35.0        |  |

3.5 x 3.5, 0.5 mm pitch

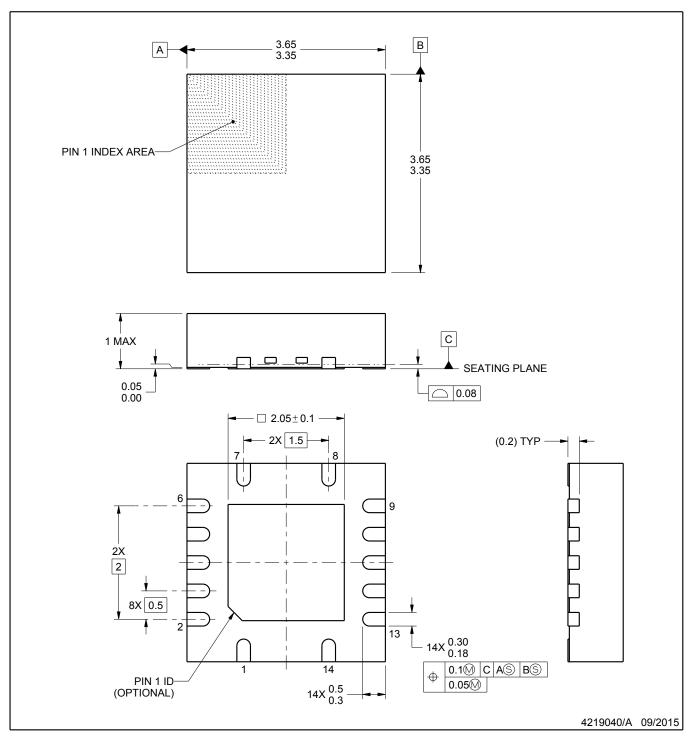
PLASTIC QUAD FLATPACK - NO LEAD

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PLASTIC QUAD FLATPACK - NO LEAD

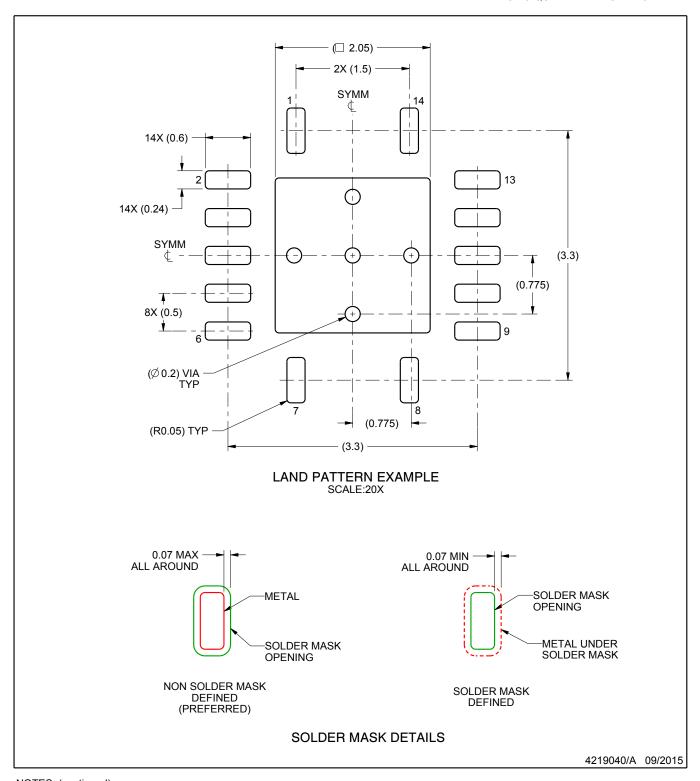


#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
  The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

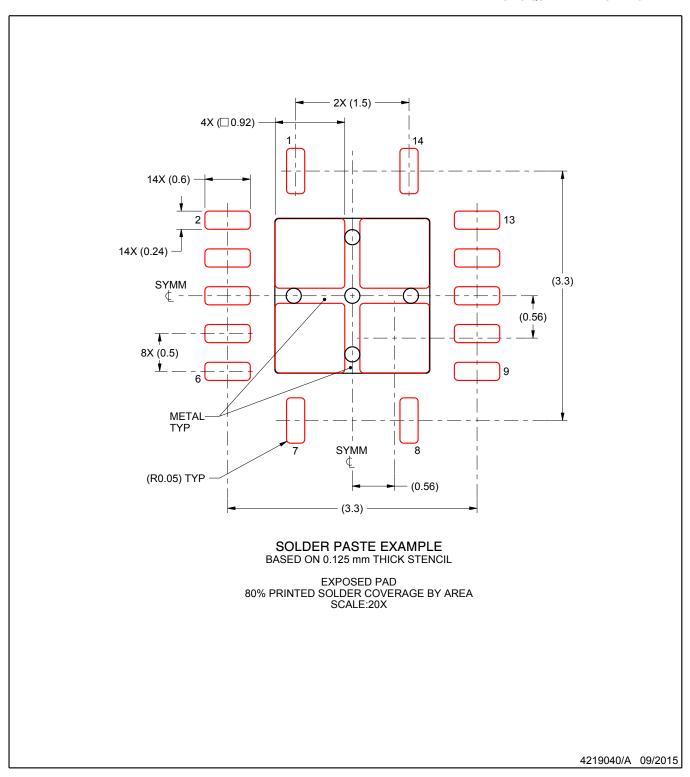


NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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